# TOSHIBA

**Preliminary** 

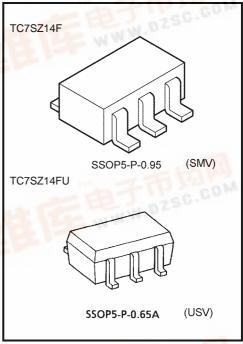
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SZ14F,TC7SZ14FU

#### Schmitt Inverter

#### **Features**

- High output drive:  $\pm 24$  mA (min) @V<sub>CC</sub> = 3 V
- High speed:  $t_{pd} = 3.7 \text{ ns (typ.)} @V_{CC} = 5 \text{ V}, 50 \text{ pF}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 1.65 to 5.5 V
- High latch-up immunity: Higher than or equal to ±500 mA
- High ESD: Higher than or equal to ±200 V (JEITA) : Higher than or equal to ±2000 V (MIL)
- Power-down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX Series when operated at 3.3 V



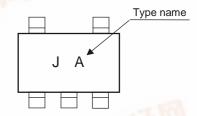
Weight:

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A: 0.006 g (typ.)

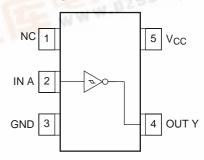
## **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit	
Supply voltage range	Vcc	-0.5 to 6	V	
DC input voltage	VIN	-0.5 to 6	V	
DC output voltage	Vout	-0.5 to 6	V	
Input diode current	lık	-20	mA	
Output diode current	lok	-20	mA	
DC output current	lout	±50	mA	
DC V <sub>CC</sub> /ground current	Icc	±50	mA	
Power dissipation	P <sub>D</sub>	200	mW	
Storage temperature	T <sub>stg</sub>	-65 to 1 <mark>50</mark>	°C	
Lead temperature (10 s)	TL	260	°C	
网络库 <sup>电</sup>	WW.DZSC.	C () NA	•	

#### Marking



#### Pin Assignment (top view)







# **Logic Diagram**

## **Truth Table**



Α	Υ
L	Н
Н	L

## **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	1.65 to 5.5	V	
Supply voltage	VCC	1.5 to 5.5 (Note 1)		
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	Vout	0 to 5.5 (Note 2)	V	
Output voltage	VOU1	0 to V <sub>CC</sub> (Note 3)	V	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	

Note 1: Date retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or Low State

#### **Electrical Characteristics**

#### **DC Electrical Characteristics**

Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Onaracteristics Symbol		rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
Positive threshold voltage			1.65	0.6	1.0	1.4	0.65	1.4	-
	V <sub>P</sub>	_	1.8	0.7	1.1	1.5	0.7	1.5	
			2.3	1.0	1.4	1.8	1.0	1.8	
			3.0	1.3	1.75	2.2	1.3	2.2	
			4.5	1.9	2.45	3.1	1.9	3.1	
			5.5	2.2	2.9	3.6	2.2	3.6	V
	V <sub>N</sub>		1.65	0.2	0.5	0.8	0.2	0.8	
			1.8	0.25	0.55	0.9	0.25	0.9	
Negative threshold voltage			2.3	0.40	0.75	1.15	0.40	1.15	
Negative tillesiloid voltage			3.0	0.6	1.0	1.5	0.6	1.5	
			4.5	1.0	1.43	2.0	1.0	2.0	
			5.5	1.2	1.70	2.4	1.2	2.4	
			1.65	0.1	0.48	0.9	0.1	1.0	
Hysteresis voltage			1.8	0.15	0.54	1.0	0.15	1.0	
	VH		2.3	0.25	0.65	1.1	0.25	1.1	\ /
			3.0	0.4	0.77	1.2	0.4	1.2	V
			4.5	0.6	1.01	1.5	0.6	1.5	-
			5.5	0.7	1.18	1.7	0.7	1.7	

# **TOSHIBA**

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol	1621	Sorialilon	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Omi
High-level output voltage			I <sub>OH</sub> = -100 μA	1.65	1.55	1.65		1.55	_	
				1.8	1.7	1.8		1.7	_	
				2.3	2.2	2.3	_	2.2		
				3.0	2.9	3.0		2.9	_	
	V <sub>OH</sub>	$V_{IN} = V_{IL}$		4.5	4.4	4.5		4.4	_	
	VOH	VIN = VIL	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52		1.29		
			$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15		1.9	_	
			$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8	_	2.4	_	
			$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	_	2.3	_	
			$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2		3.8		V
		$V_{IN} = V_{IH}$	I <sub>OL</sub> = 100 μA	1.65	_	0	0.1	_	0.1	V
				1.8	_	0	0.1	_	0.1	
				2.3	_	0	0.1	_	0.1	
				3.0	_	0	0.1	_	0.1	
Low-level output voltage	V <sub>OL</sub>			4.5	_	0	0.1	_	0.1	
Low-level output voltage	VOL		I <sub>OL</sub> = 4 mA	1.65	_	0.08	0.24	_	0.24	
			I <sub>OL</sub> = 8 mA	2.3	_	0.1	0.3	_	0.3	
			I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	_	0.4	
			I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55	_	0.55	
			I <sub>OL</sub> = 32 mA	4.5	_	0.22	0.55	_	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0~5.5	_	_	±1	_	±10	μΑ
Power OFF leakage current	l <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0.0		_	1	_	10	μА
Quiescent supply current	Icc	V <sub>IN</sub> = 5.5 V or GND		1.65~5.5	_	_	1	_	10	μΑ

## AC Electrical Characteristics (Unless otherwise specified Input: $t_r = t_f = 3$ ns)

Object of the state of the stat	0	Table Oam dition		Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Onit
Propagation delay time	<sup>t</sup> pLH <sup>t</sup> pHL	KL = 1 IVIS2	1.65	2.0	9.1	15.0	2.0	15.6	ns
			1.8	2.0	7.6	12.5	2.0	13	
			$2.5\pm0.2$	1.0	5.0	9.0	1.0	9.5	
			$3.3 \pm 0.3$	1.0	3.7	6.3	1.0	6.5	
			$5.0 \pm 0.5$	0.5	3.1	5.2	0.5	5.5	
		$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$	$3.3 \pm 0.3$	1.5	4.4	7.2	1.5	7.5	
			$5.0 \pm 0.5$	0.5	3.7	5.9	0.8	6.2	
Input capacitance	C <sub>IN</sub>	_		_		_		_	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note 4)	_		_		_	pF

Note 4: CPD is defined as the value of the internal equivalent capacitance which is Calculated from the operating current consumption without load.

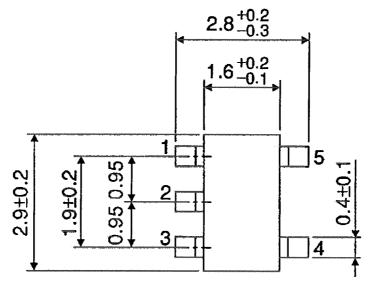
Average operating current can be obtained by the equation.

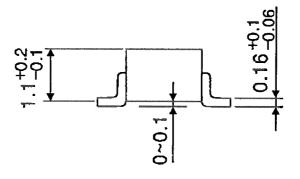
$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

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# **Package Dimensions**

SSOP5-P-0.95 Unit: mm

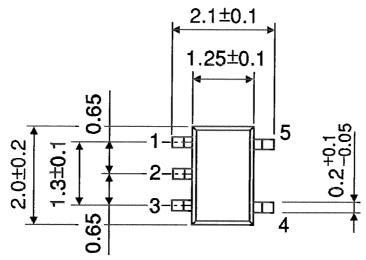


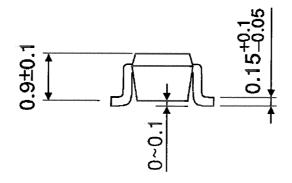


Weight: 0.016 g (typ.)

# **Package Dimensions**

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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